









 life.augmented	Hersteller-Teilenummer: STD155N3H6
	Hersteller / Marke: STMicroelectronics
	Teil der Beschreibung: MOSFET N-CH 30V 80A DPAK
	Datenblätter:  STD155N3H6.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 60100 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	STD155N3H6
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 30V 80A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	60100 pcs Stock
Serie	DeepGATE™, STripFET™ VI
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	110W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	80A (Tc)
Rds On (Max) @ Id, Vgs	3 mOhm @ 40A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3650pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































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Anfrage STD155N3H6: Info@Y-IC.com

Sie können auch interessiert sein:

 STD15N06L ST STD15N06L ST	 STD150NH02 ST STD150NH02 ST	 STD15N60M2-EP STMicroelectronics MOSFET N-CH 600V 11A EP DPAK	 STD150NH02L ST STD150NH02L ST
 STD15N50M2AG STMicroelectronics MOSFET N-CHANNEL 500V 10A DPAK	 STD15A STD STD15A STD	 STD150NH02LT4 STMicroelectronics MOSFET N-CH 24V 150A DPAK	 STD155N3LH6 STMicroelectronics MOSFET N-CH 30V 80A D2PAK

heiße Teile

Mehr

 STD130GK08B	 STD130GK12	 STD130GK12B	 STD130GK14	 STD130GK14B
 STD130GK16	 STD130GK16B	 STD130GK18	 STD130N4F6AG	 STD130N6F7
 STD130N6F7	 STD134N4F7AG	 STD13N60M2	 STD13N65M2	 STD13NM60N
 STD13NM60NT4	 STD140N6F7	 STD14NM50N	 STD14NM60N	 STD1501-ADJM-TRG
 STD150N3LLH6	 STD150NH02	 STD150NH02L	 STD150NH02L-1	 STD150NH02LT4
 STD155N3LH6	 STD15N06L	 STD15N65M5	 STD15NF06L	 STD15NF10
 STD15NF10T4	 STD15P6F6AG	 STD160-1	 STD165GK08	 STD165GK08B
 STD165GK12	 STD165GK12B	 STD165GK14	 STD165GK14B	 STD165GK16
 STD165GK16B	 STD165GK18	 STD165GK18B	 STD1664Y	 STD16N10LT4
 STD16N65M5	 STD16NE06	 STD16NE06L	 STD16NE06L-1	 STD16NE06LT4

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